

# Building Blocks and Sub-Circuits with Magnetic Field Generators

Team sdmay23-29

Members:

Andrew Murphy [EE]

William Nichols [EE]

Michael Lopez [EE]

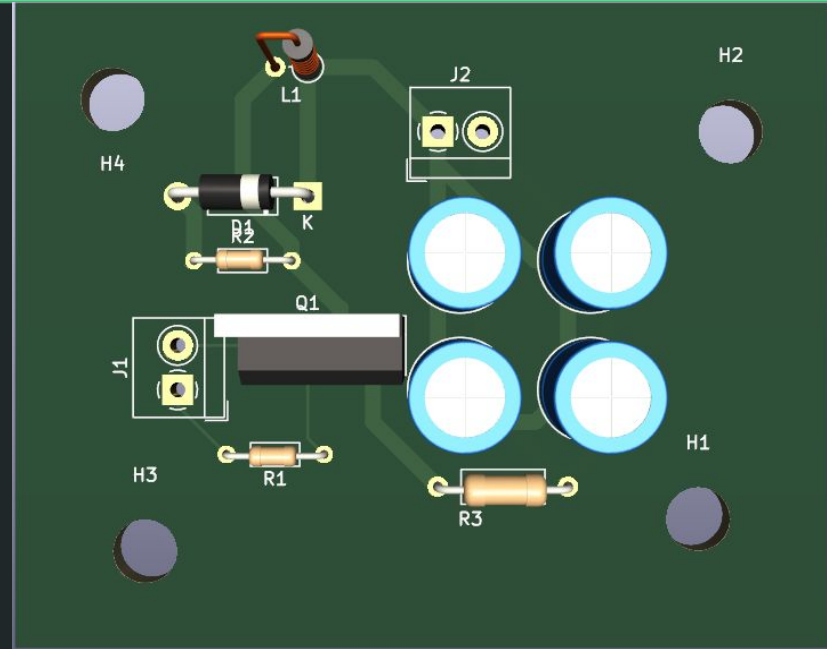
Steven Huynh [EE]

Umair Sarwar [EE]

Client: Wei Shen Theh

Advisors: Mani Mina, Robert Bouda

Date: 12/8/22



3D Model of PCB

# Project Introduction

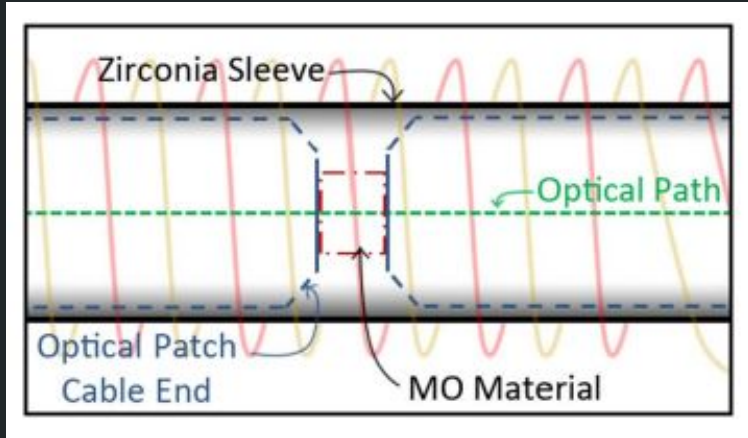
## Context

Our project consists of designing a magnetic field generator (MFG) with a focus on optical design/simulation.

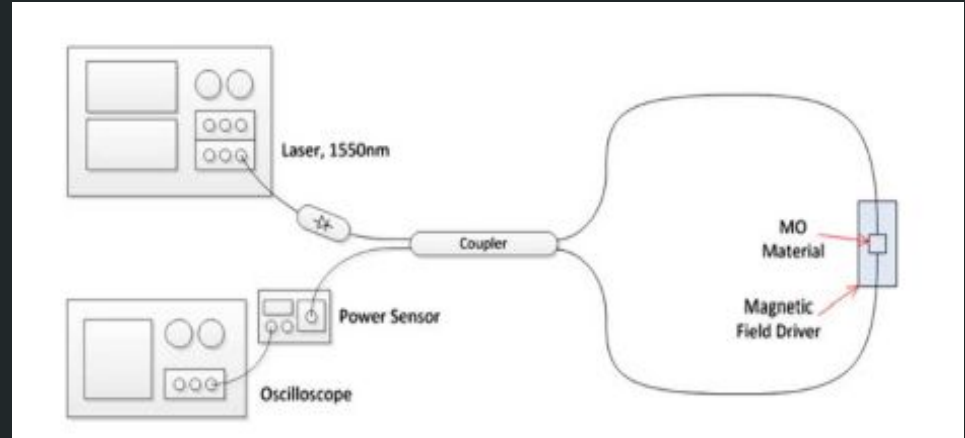
## Problem Statement

Our goal is to enhance the MFG circuits of past senior design projects and create our own optical simulation with various softwares.

# Optical Simulation

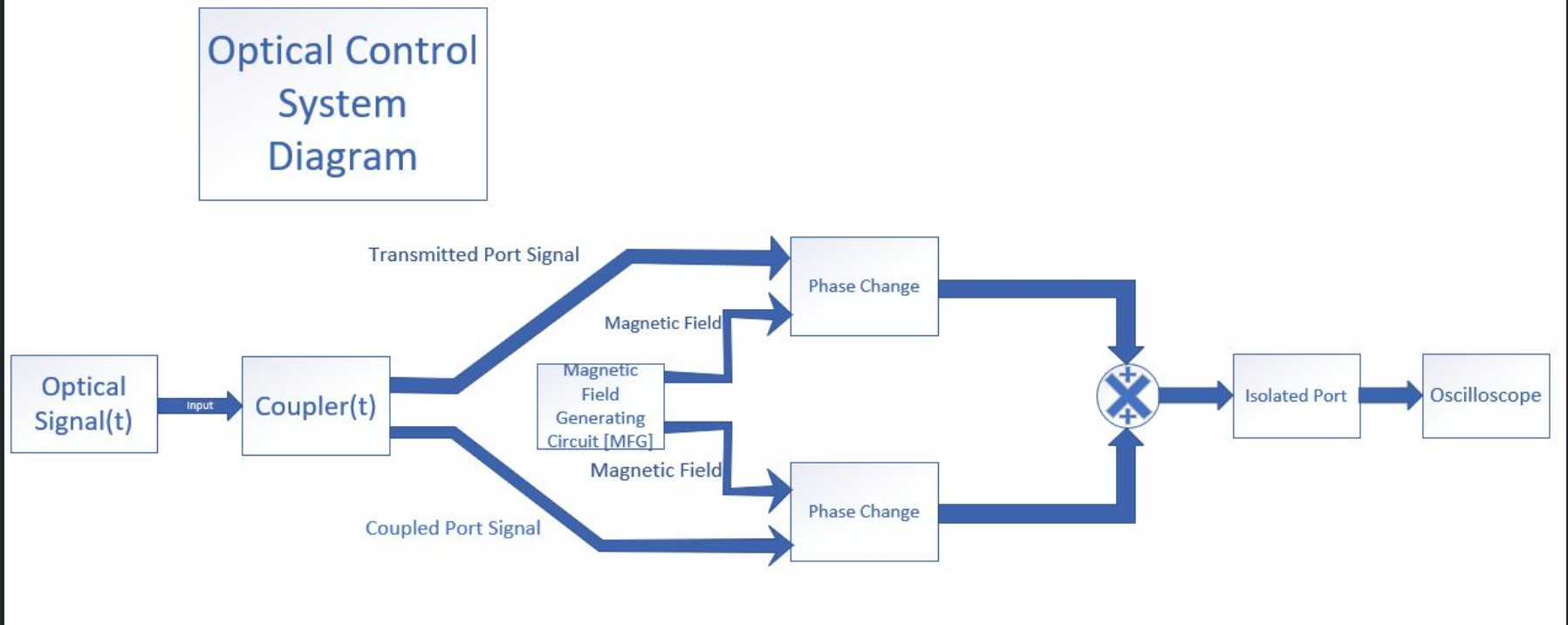


MO material between two optical patch cable ends, fitted within the mating sleeve.



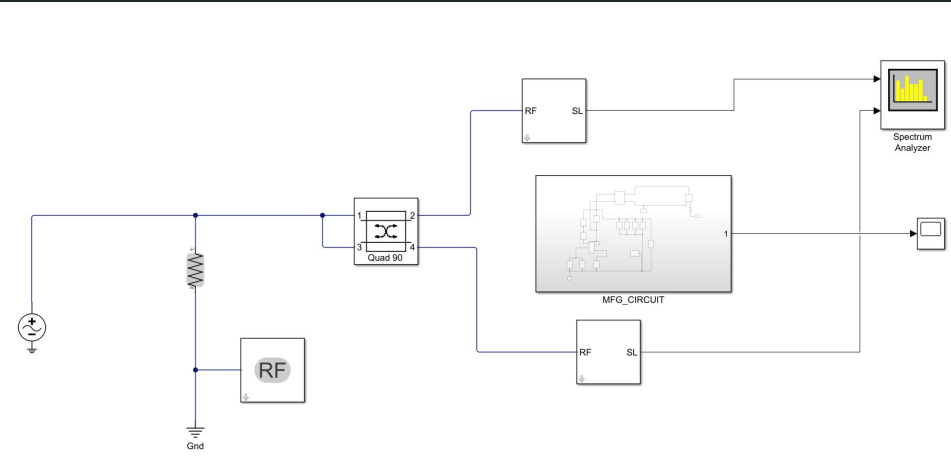
Fiber-based Magneto-Optic (MO) Sagnac interferometer setup.

# Optical Simulation

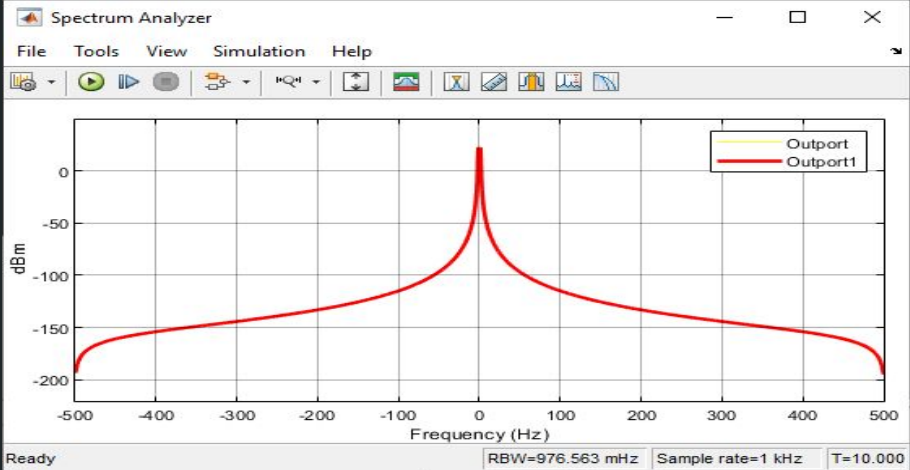


# Optical Simulation In MATLAB (Work In Progress)

## Overall Optical Simulation



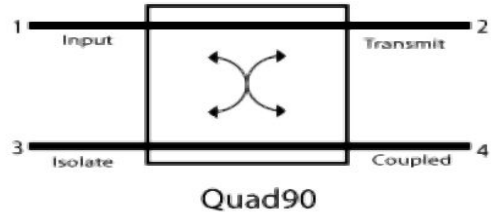
Coupler S Parameters



Ready RBW=976.563 mHz Sample rate=1 kHz T=10.000

$$\begin{bmatrix}
 0 & -j/\sqrt{2} & 0 & -1/\sqrt{2} \\
 -j/\sqrt{2} & 0 & -1/\sqrt{2} & 0 \\
 0 & -1/\sqrt{2} & 0 & -j/\sqrt{2} \\
 -1/\sqrt{2} & 0 & -j/\sqrt{2} & 0
 \end{bmatrix}$$

S



# Inductor Design

$$B = \frac{\mu_0 N I}{\sqrt{l^2 + 4r^2}}$$

$$L = \frac{\mu_0 N^2 \pi r^2}{\sqrt{l^2 + 4r^2}}$$

$N = 4$  turns

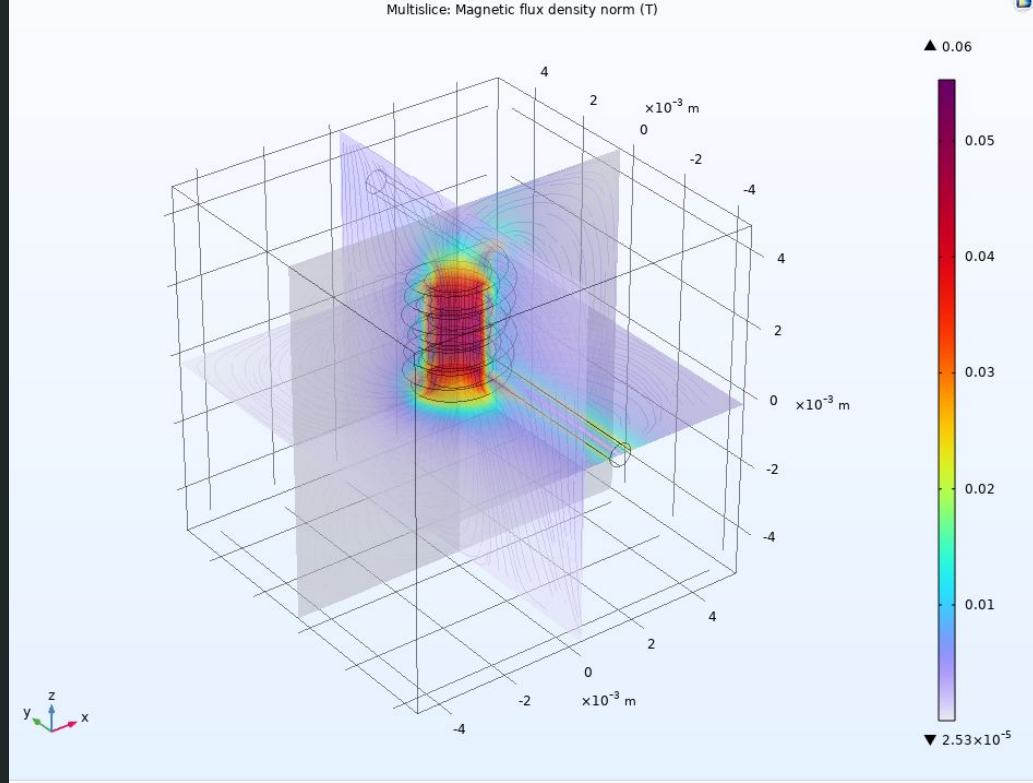
$r = 1.1$  mm

$l = 3.5$  mm

$$\mu_0 = 4\pi * 10^{-7} \text{ H/m}$$

*Calculated Inductance = 20.2 nH*

*Inductance Calculated in COMSOL = 21.73 nH*



Magnetic Flux Density of Inductor in COMSOL

“39 • fast, compact, High Strength Magnetic Pulse Generator,” *sdmay22*. [Online]. Available: <http://sdmay22-39.sd.ece.iastate.edu/>. [Accessed: 05-Dec-2022].

# Circuit Design

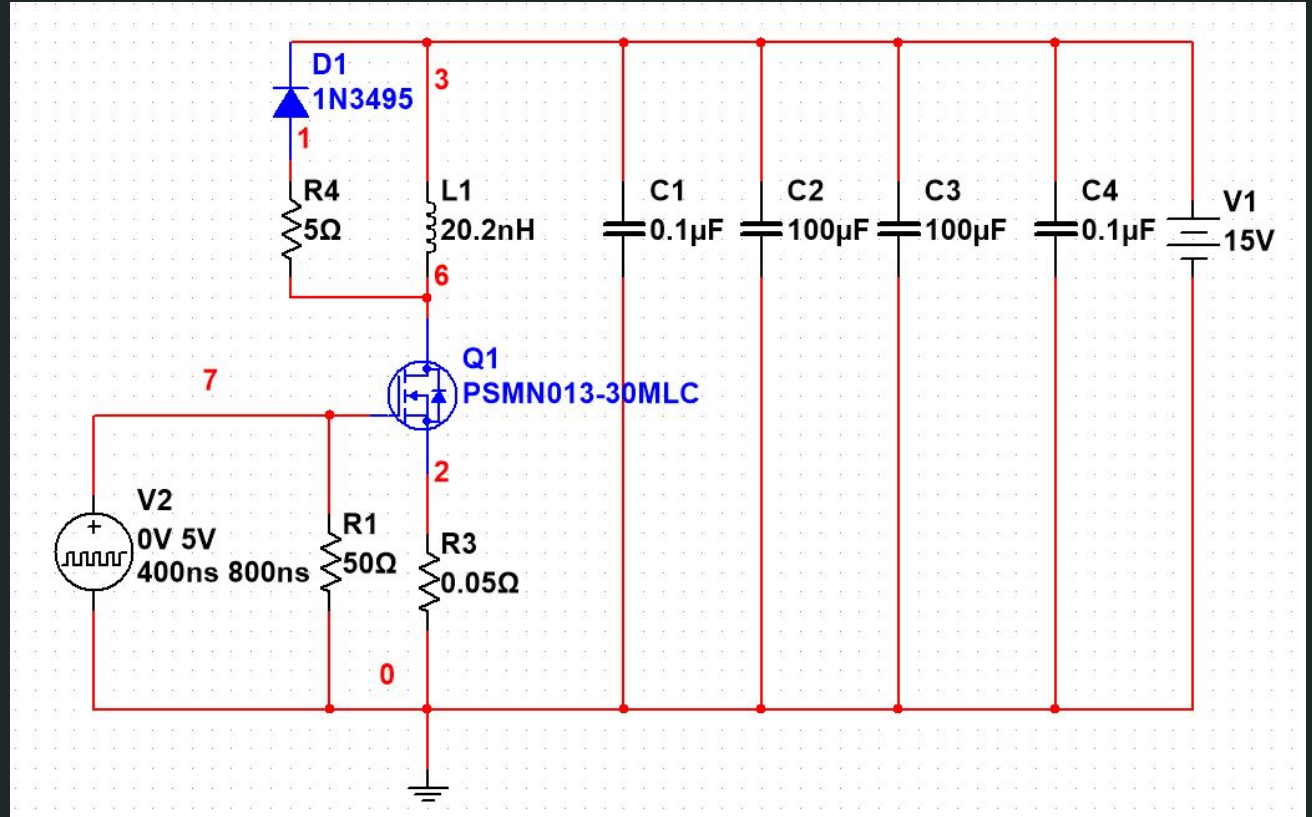
Circuit Specs:

VDC -  $\leq 15V$

Flux Density -  $> 500 G$

Rise Time -  $< 100 ns$

PCB Size - 3.5" x 2"

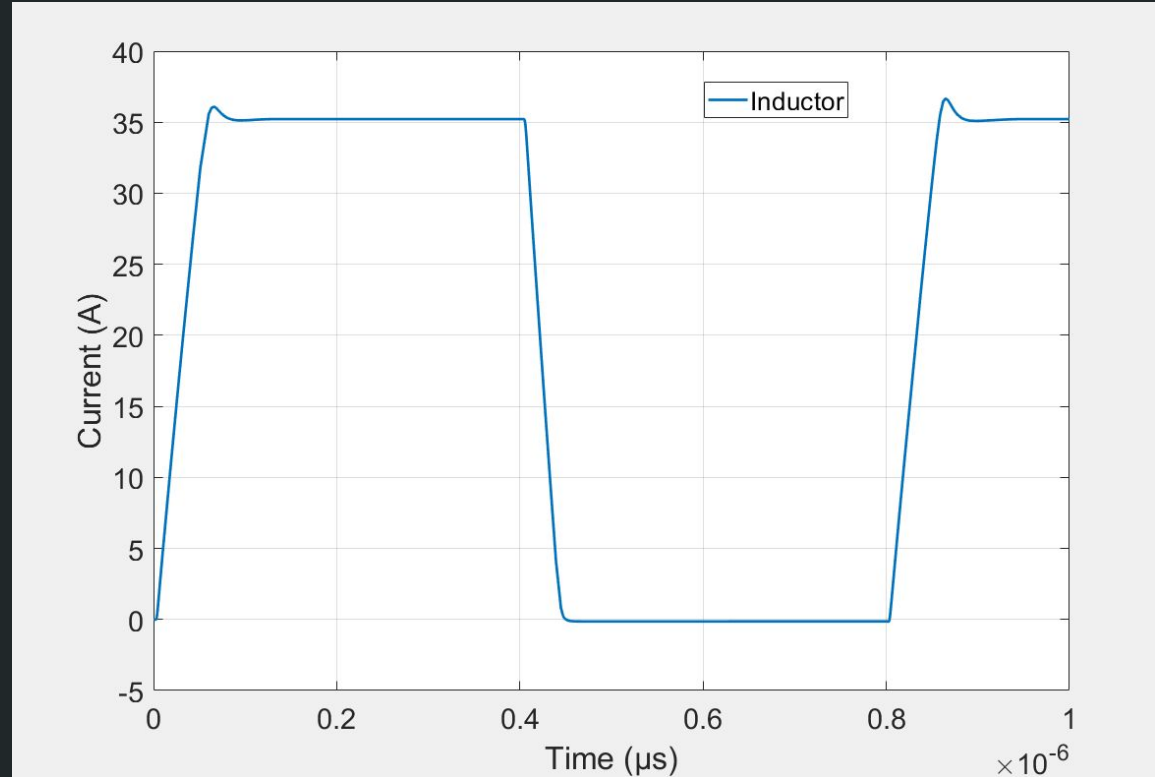


Schematic of MFG Circuit

# Circuit Simulation Results

Rise Time - 42.6 ns

Transient Simulation  
of MFG Circuit





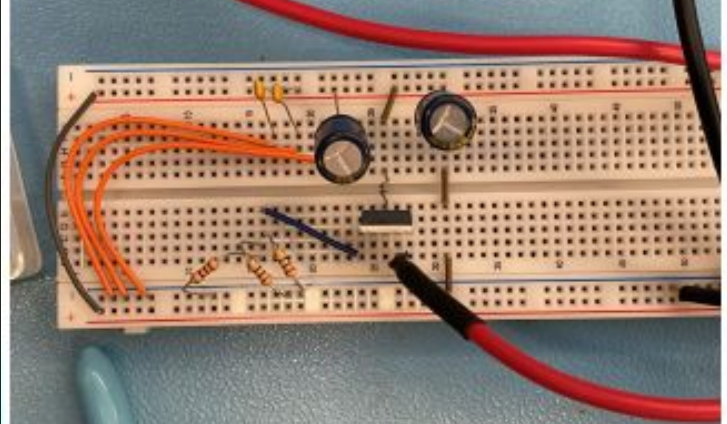
Oscilloscope measurements

# Initial Testing

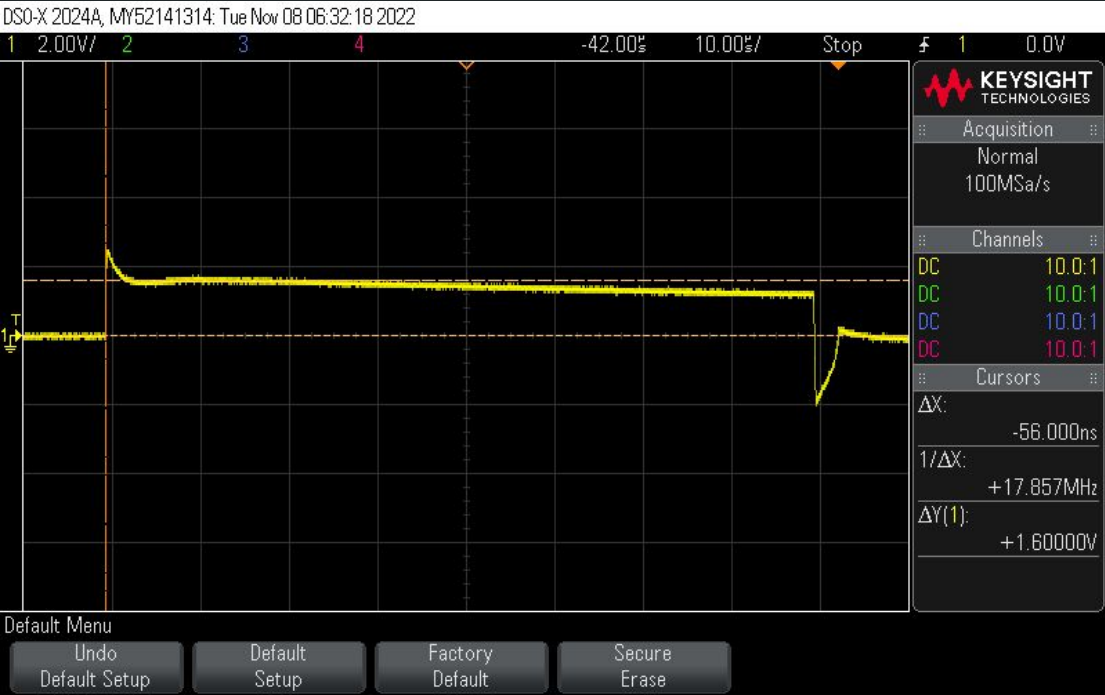
Rise Time - 56 ns

X axis - Time

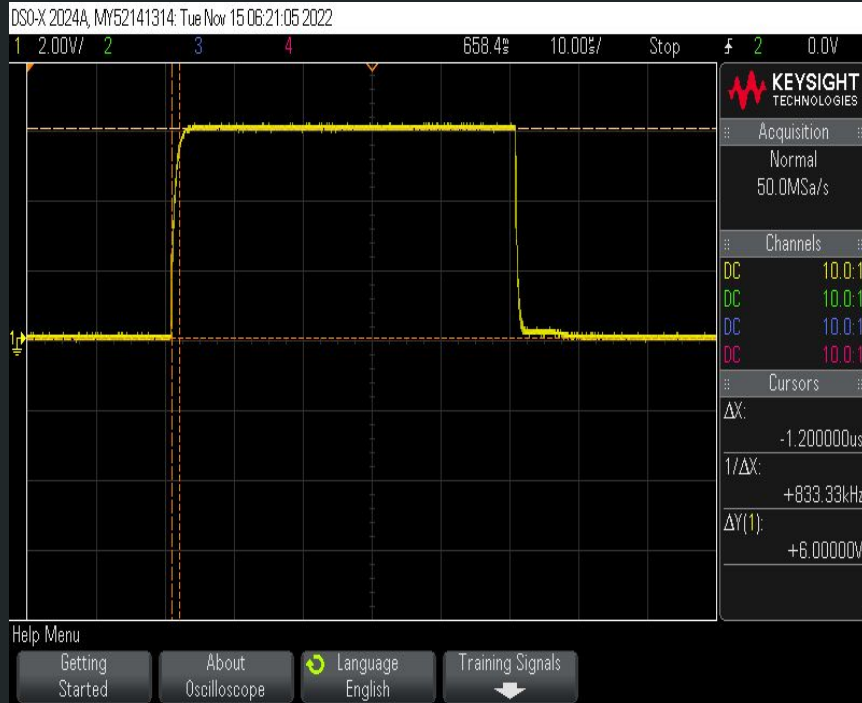
Y axis - Voltage



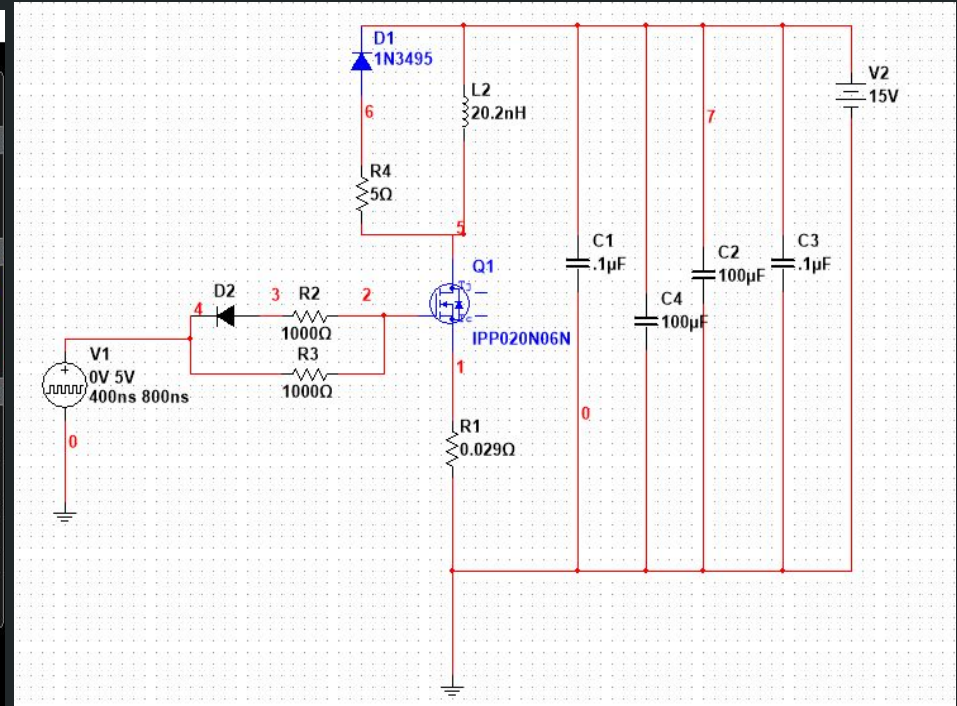
Prototype circuit



# Initial Testing



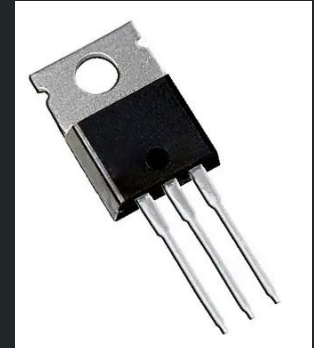
New Oscilloscope measurements



New Schematic of MFG Circuit

# MOSFET Figure of Merit

	IRF540 (TH)	PSMN013-30MLC (SM)
$V_{DS}$ (V)	100	30
$I_{Pulse}$ (A)	110	157
$C_{IN}$ (pF)	1700	519
$t_{rise}$ (ns)	44	9.8
$Q_{GD}$ (nC)	32	1
$R_{DS}$ (m $\Omega$ )	77	17
$R_{DS} \times Q_{GD}$	2464	17



J. Strydom, "eGaN™ N -Silicon Power Shoot-Out: Comparing Figure of Merit (FOM) ", ed. Power Electronics Technology, 2010

# Conclusion

According to our advisors we are on track

Our plan for next semester is the following

- Complete our optical simulation
- Finalized part selection by testing out various components in our circuit design
- Complete and test our PCB design

# References

- "39 • fast, compact, High Strength Magnetic Pulse Generator," *sdmay22*. [Online]. Available: <http://sdmay22-39.sd.ece.iastate.edu/>. [Accessed: 05-Dec-2022].
- J. Strydom, "eGaNTM N -Silicon Power Shoot-Out: Comparing Figure of Merit (FOM) ", ed. Power Electronics Technology, 2010
- J. W. Pritchard, M. Mina and R. J. Weber, "Improved Switching for Magneto-Optic Fiber-Based Technologies," in *IEEE Transactions on Magnetics*, vol. 48, no. 11, pp. 3772-3775, Nov. 2012, doi: 10.1109/TMAG.2012.2202275.